

#### 120V NPN MEDIUM POWER DARLINGTON TRANSISTOR IN SOT23F

#### **Features**

- BV<sub>CEO</sub> > 120V
- I<sub>C</sub> = 1A Continuous Collector Current
- V<sub>CE(SAT)</sub> < 1.5V @ 1A</li>
- R<sub>CE(SAT)</sub> = 38mΩ
- 1.5W Power Dissipation
- Complementary PNP Type: ZXTP05120FF
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23F
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.012 grams (Approximate)

### **Description**

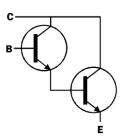
This high performance NPN Darlington transistor is housed in the small outline SOT23 flat package for applications where space is at a premium.

### **Applications**

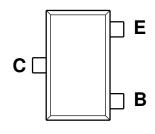
- · Lamp, Relay and Solenoid Drive
- Lighting







Device Symbol



Top View Pin Configuration

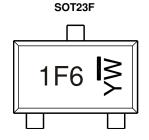
#### **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTN04120HFFTA	AEC-Q101	1F6	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



1F6 = Product Type Marking Code YW = Date Code Marking

 $\frac{Y}{M}$  = Year : 0~9

W = Week : A~Z : 1~26 a~z : 27~52

z represents 52 & 53 week



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	140	V
Collector-Emitter Voltage	$V_{\sf CEO}$	120	V
Emitter-Base Voltage	$V_{EBO}$	10	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	Ісм	4	Α
Base Current	Ι <sub>Β</sub>	0.5	Α

# Thermal Characteristics (@ $T_A = \pm 25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		0.84 6.72		
Power Dissipation	(Note 6)	P <sub>D</sub>	1.34 10.72	W mW/°C	
Linear Derating Factor	(Note 7)		1.50 12.0		
	(Note 8)		2.0 16.0		
	(Note 5)		149	°C/W	
The weed Decistors and Investigate Australia	(Note 6)	Б	93		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	83	- C/VV	
	(Note 8)		60		
Thermal Resistance, Junction to Lead (Note 9)		R <sub>0JL</sub>	43.8	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 10)

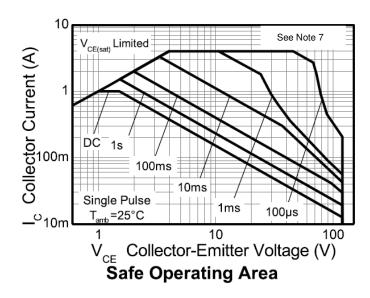
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge – Machine Model	ESD MM	200	V	В

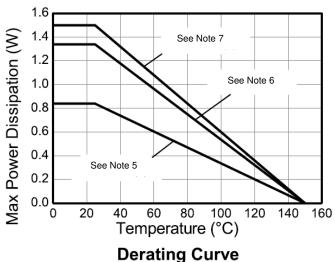
Notes:

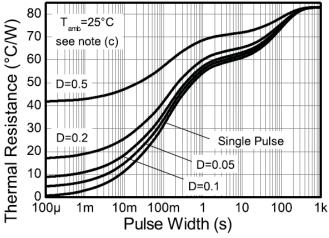
- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
- Same as Note 7, whilst measured at t < 5 seconds.</li>
  Thermal resistance from junction to solder-point (at the end of the collector lead).
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.



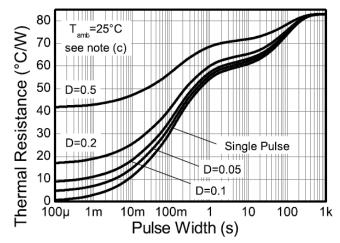
## **Thermal Characteristics and Derating Information**











**Transient Thermal Impedance** 



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

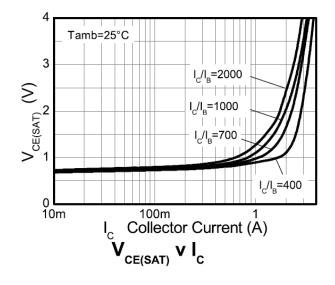
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	$BV_CBO$	140	300	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Base Open) (Note 11)	BV <sub>CEO</sub>	120	140	_	٧	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	10	16	_	V	$I_E = 100\mu A$
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	<1 —	100 10	nΑ μΑ	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	<0.1	10	μΑ	V <sub>CE</sub> = 120V
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	<1	100	nA	$V_{EB} = 8V$
ON CHARACTERISTICS (Note 11)						
Static Forward Current Transfer Ratio	h <sub>FE</sub>	3k 3k 3k 1k	11k 12k 10k 5k	 30k 	_	$\begin{split} & I_{C} = 50 \text{mA}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 500 \text{mA}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 1 \text{A}, \ V_{CE} = 5 \text{V} \\ & I_{C} = 2 \text{A}, \ V_{CE} = 5 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (SAT)	_	0.8 1.1 1.1	0.9 1.5 1.5	V	$I_C = 250$ mA, $I_B = 25$ mA $I_C = 1$ A, $I_B = 1$ mA $I_C = 2$ A, $I_B = 5$ mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	1.55	1.7	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 1mA
Base-Emitter On Voltage	V <sub>BE(ON)</sub>	_	1.45	1.7	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V
SMALL SIGNAL CHARACTERISTICS	,		•	•		•
Transition Frequency	f⊤	_	120	_	MHz	$I_C = 100 \text{mA}, V_{CE} = 10 \text{V},$ f = 20 MHz
Input Capacitance	C <sub>IBO</sub>	_	68	90	рF	$V_{EB} = 500 \text{mV}, f = 1 \text{MHz}$
Output Capacitance	$C_{OBO}$		12.8	25	рF	$V_{CB} = 10V$ , $f = 1MHz$
Delay Time	$t_D$		507	_	ns	101
Rise Time	t <sub>R</sub>	_	136	_	ns	$V_{CC} = 10V$ , $I_{C} = 500$ mA,
Storage Time	t <sub>S</sub>		910	_	ns	$I_{B1} = -I_{B2} = 0.5 \text{mA}$
Fall Time	t <sub>F</sub>	_	369	_	ns	181 – 182 – 0.5IIIA

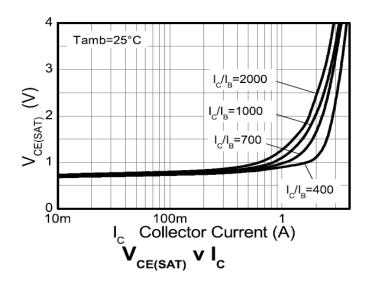
Note:

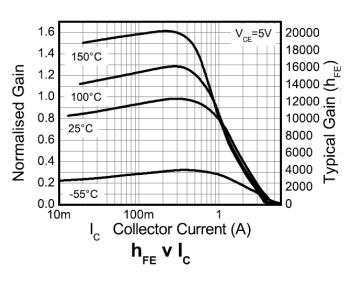
11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

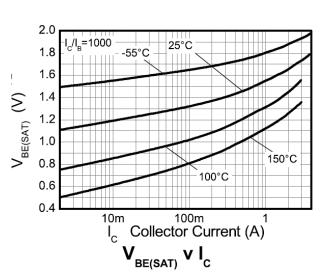


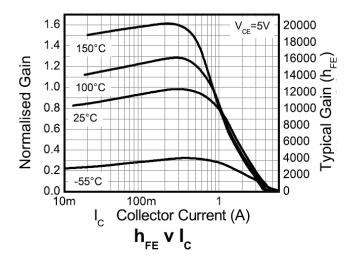
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







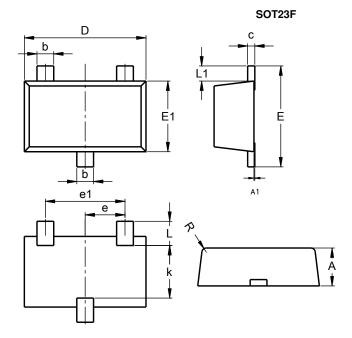






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

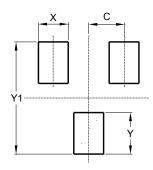


SOT23F						
Dim	Min	Max	Тур			
Α	0.80	1.00	0.90			
b	0.35	0.50	0.44			
C	0.10	0.20	0.16			
D	2.80 3.00 2.90					
е	0.95 REF					
e1	0.190 REF					
Е	2.30	2.50	2.40			
E1	1.50	1.70	1.65			
k	1.20 – –					
L	0.30 0.65 0.50					
L1	0.30	0.50	0.40			
R	0.05	0.15	_			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23F



Dimensions	Value			
Dimensions	(in mm)			
С	0.95			
Х	0.80			
Υ	1.110			
Y1	3.000			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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